Nch 600V 2A Power MOSFET

V _{DSS}	600V
R _{DS(on)} (Max.)	3.4Ω
I _D	±1.7A
P _D	26W

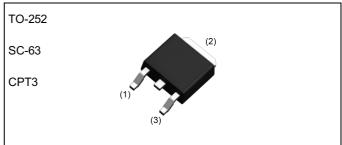
Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (V_{GSS}) guaranteed to be $\pm 20V$.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.
- 6) Pb-free lead plating; RoHS compliant

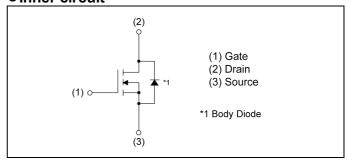
Application

Switching Power Supply

Outline



•Inner circuit



Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	16
-	Basic ordering unit (pcs)	2500
	Taping code	TL
	Marking	R6002E

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V_{DSS}	600	V
Ocation and desire assessed	T _C = 25°C	I _D *1	±1.7	Α
Continuous drain current	T _C = 100°C	I _D *1	±0.9	Α
Pulsed drain current	I _{DP} *2	±4	Α	
Gate - Source voltage		V_{GSS}	±20	V
Avalanche current, repetitive		I _{AR}	0.3	Α
Avalanche energy, single pulse		E _{AS} *3	6	mJ
Avalanche energy, repetitive		E _{AR} *3	0.04	mJ
Power dissipation (T _c = 25°C)		P _D	26	W
Junction temperature	T _j	150	°C	
Operating junction and storage temperature range		T _{stg}	-55 to +150	°C
Reverse diode dv/dt	dv/dt*4	15	V/ns	

● Absolute maximum ratings

Parameter	Symbol	Conditions	Values	Unit
Drain - Source voltage slope	dv/dt	V _{DS} = 480V T _j = 25°C	50	V/ns

●Thermal resistance

Doromotor	Symbol	Values			Unit
Parameter	Symbol	Min.	Тур.	Max.	UTIIL
Thermal resistance, junction - case	R _{thJC}	-	-	4.9	°C/W
Thermal resistance, junction - ambient	R _{thJA} *5	-	-	147	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	-	265	°C

• Electrical characteristics $(T_a = 25^{\circ}C)$

Parameter	Cumb al	Conditions	Values			Unit
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	600	-	-	V
		V _{DS} = 600V, V _{GS} = 0V				
Zero gate voltage drain current	I _{DSS}	$T_j = 25^{\circ}C$	-	0.1	100	μΑ
		$T_j = 125^{\circ}C$	-	-	1000	
Gate - Source leakage current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V	-	-	±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} = 10V, I _D = 1mA	2	-	4	V
		V _{GS} = 10V, I _D = 0.5A				
Static drain - source on - state resistance	R _{DS(on)} *6	$T_j = 25^{\circ}C$	-	2.8	3.4	Ω
		T _j = 125°C	-	6.0	-	
Gate resistance	R_{G}	f = 1MHz, open drain	-	15.0	-	Ω

● Electrical characteristics (T_a = 25°C)

Dovometer	Cumbal	Conditions	Values			Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Transconductance	g _{fs} *6	$V_{DS} = 10V, I_D = 0.85A$	0.5	1.0	-	S
Input capacitance	C _{iss}	V _{GS} = 0V	-	65	-	
Output capacitance	C _{oss}	V _{DS} = 25V	-	100	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	12	-	
Effective output capacitance, energy related	C _{o(er)}	V _{GS} = 0V,	-	6.4	-	_
Effective output capacitance, time related	C _{o(tr)}	V _{DS} = 0V to 480V	-	21	-	pF
Turn - on delay time	t _{d(on)} *6	$V_{DD} \simeq 300V$, $V_{GS} = 10V$	-	12	-	
Rise time	t _r *6	I _D = 0.85A	-	16	-	no
Turn - off delay time	t _{d(off)} *6	R _L ≃ 357Ω	-	25	-	ns
Fall time	t _f *6	$R_G = 10\Omega$	-	60	-	

● Gate charge characteristics (T_a = 25°C)

Davanastan	O and the area		Values			1.1
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	Q _g *6	V _{DD} ≈ 300V	-	6.5	-	
Gate - Source charge	Q _{gs} *6	I _D = 1.7A	-	1.7	-	nC
Gate - Drain charge	Q _{gd} *6	V _{GS} = 10V	-	3.0	-	
Gate plateau voltage	V _(plateau)	V _{DD} ≈ 300V, I _D = 1.7A	-	6.0	-	V

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw \leq 10µs, Duty cycle \leq 1%

^{*3} I_D=0.3A, V_{DD}=50V

^{*4} Reference measurement circuits Fig.5-1.

^{*5} Mounted on a epoxy PCB FR4 (20mm×20mm×0.8mm).

^{*6} Pulsed

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Cumbal	Conditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic	
Continuous forward current	I _S *1	T _C = 25°C	1	1	1.7	А	
Pulse forward current	I _{SP} *2	1C - 25 C	-	-	4	Α	
Forward voltage	V _{SD} *6	$V_{GS} = 0V, I_{S} = 1.7A$	-	-	1.5	V	
Reverse recovery time	t _{rr} *6		-	240	-	ns	
Reverse recovery charge	Q _{rr} *6	I _S = 1.7A di/dt = 100A/µs	-	0.86	-	μC	
Peak reverse recovery current	I _{mm} *6	α,, ατ 100/ υμο	-	7.0	-	Α	

Typical transient thermal characteristics

Symbol	Value	Unit
R _{th1}	1.95	
R _{th2}	2.54	K/W
R _{th3}	22.4	r\/vv
R _{th4}	48.3	

Symbol	Value	Unit
C _{th1}	0.000735	
C _{th2}	0.00802	Malk
C _{th3}	0.104	Ws/K
C _{th4}	1.20	

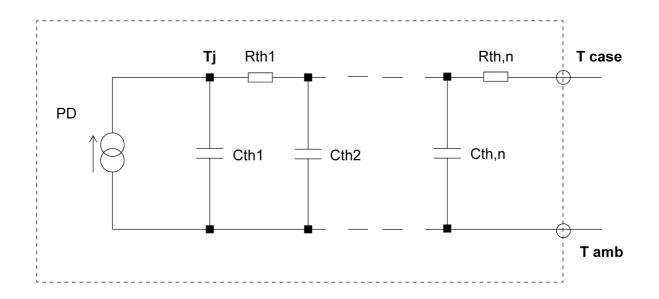


Fig.1 Power Dissipation Derating Curve

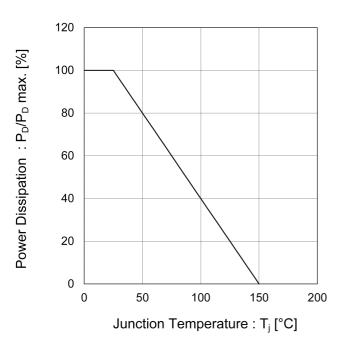


Fig.2 Normalized Transient Thermal Resistance vs. Pulse Width

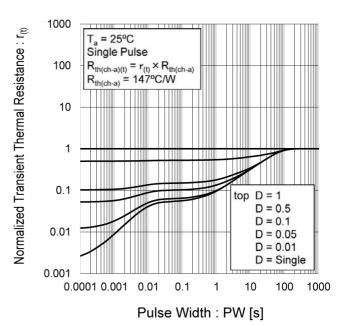


Fig.3 Avalanche Energy Derating Curve vs Junction Temperature

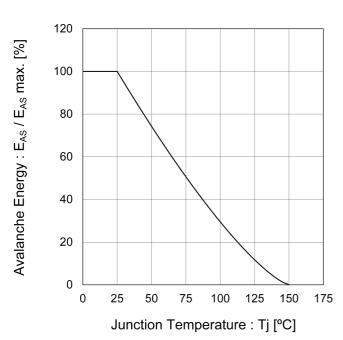


Fig.4 Typical Output Characteristics(I)

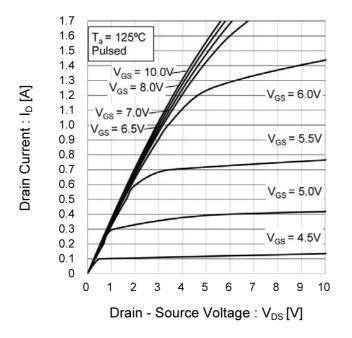


Fig.5 Typical Output Characteristics(II)

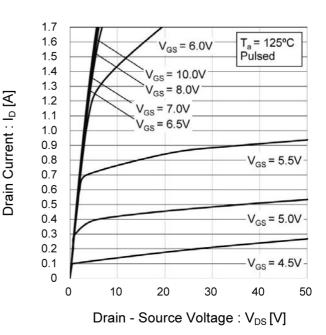


Fig.6 Tj = 150°C Typical Output Characteristics (I)

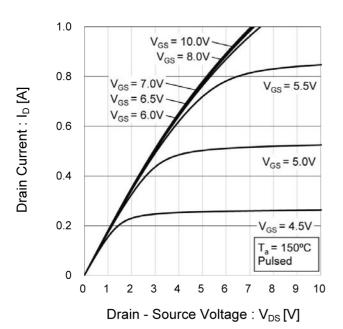
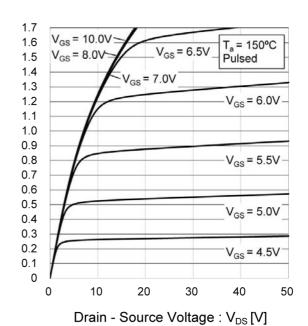


Fig.7 Tj = 150°C Typical Output Characteristics (II)



Drain Current : I_D [A]

Fig.8 Breakdown Voltage vs. Junction Temperature

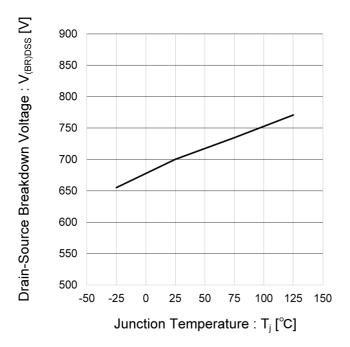


Fig.9 Typical Transfer Characteristics

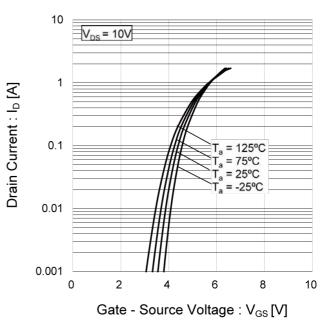


Fig.10 Gate Threshold Voltage vs.Junction Temperature

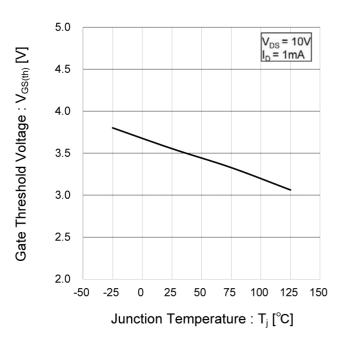
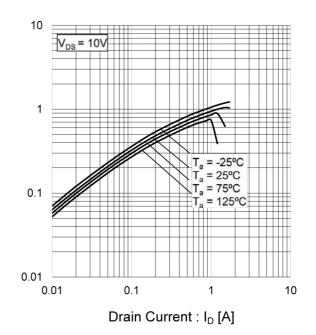


Fig.11 Transconductance vs. Drain Current



Transconductance : grs [S]

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

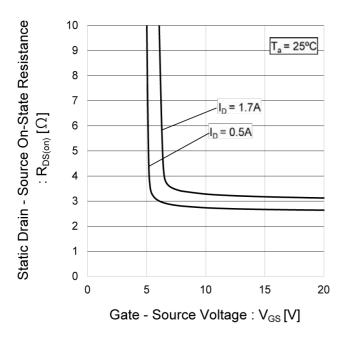


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

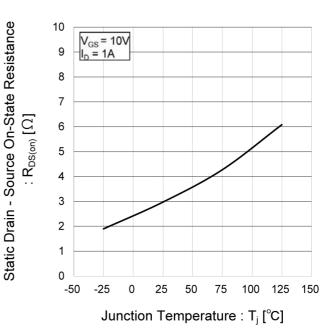


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current(I)

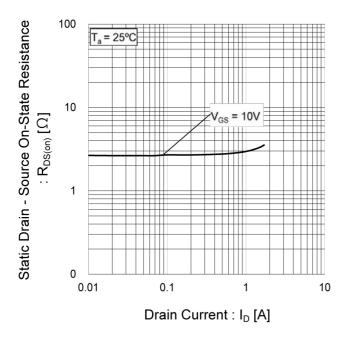


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

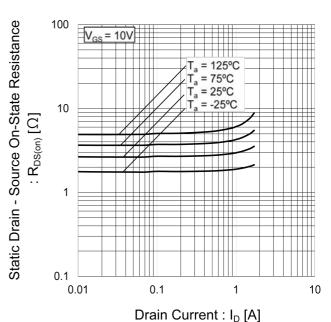


Fig.16 Typical Capacitance vs. Drain - Source Voltage

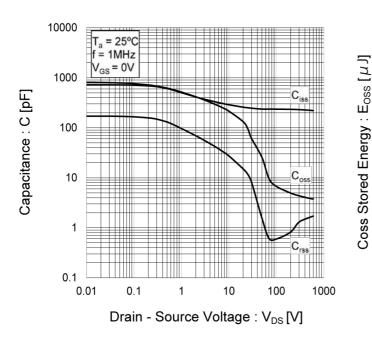


Fig.17 Coss Stored Energy

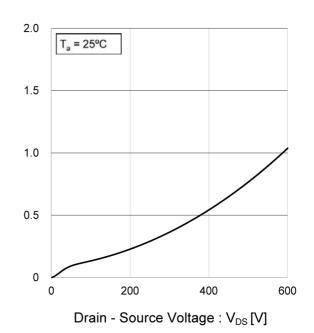


Fig.18 Switching Characteristics

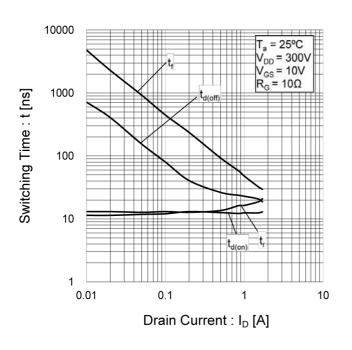
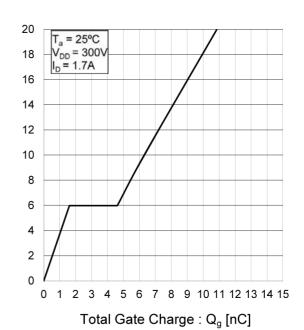


Fig.19 Dynamic Input Characteristics



Gate - Source Voltage : V_{GS} [V]

Fig.20 Inverse Diode Forward Current vs. Source - Drain Voltage

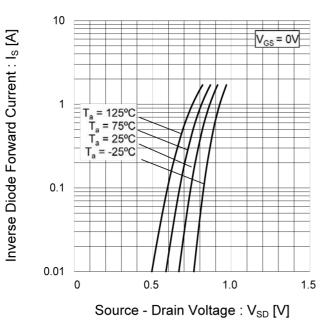
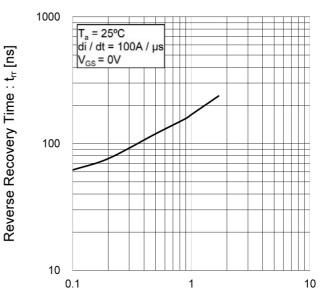


Fig.21 ReverForward Currentse Recovery Time vs. Inverse Diode



Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

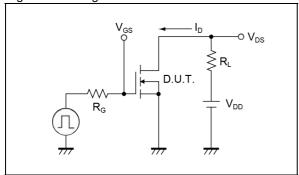


Fig.2-1 Gate Charge Measurement Circuit

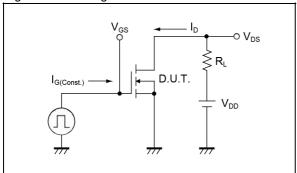


Fig.3-1 Avalanche Measurement Circuit

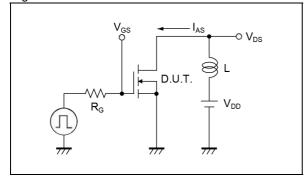


Fig.1-2 Switching Waveforms

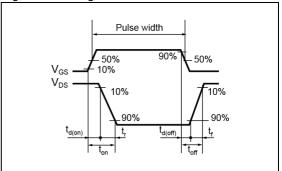


Fig.2-2 Gate Charge Waveform

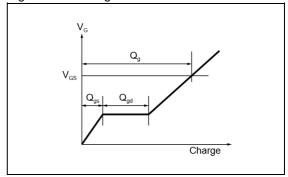
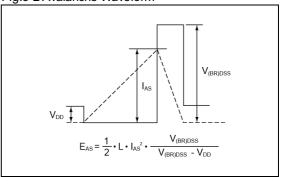
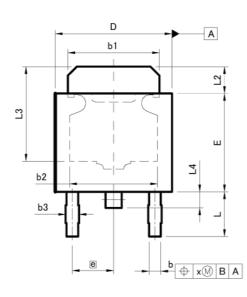


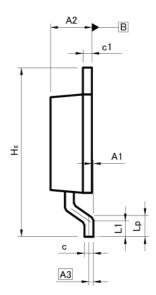
Fig.3-2 Avalanche Waveform

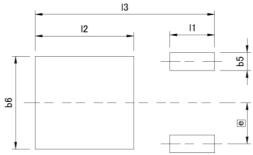


Dimensions









Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
- F(3)(6)	MIN	MAX	MIN	MAX
A1	0.00	0.15	0.000	0.006
A2	2.20	2.50	0.087	0.098
A3	0.	25	0.0	10
b	0.55	0.75	0.022	0.030
b1	5.00	5.30	0.197	0.209
b2	4.	90	0.1	93
b3	0.	75	0.0	30
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
E	5.40	5.80	0.213	0.228
е	2.	30	0.0	91
HE	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.110
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3		30	0.2	
L4	0.	90	0.0	35
Lp	1.00	1.60	0.039	0.063
х	7.22	0.25	772	0.010

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b5	_	1.00		0.04
b6	100 to	5.20		0.205
11	-	2.50	-	0.098
12		5.50		0.217
13	-	10.00	140	0.394

Dimension in mm/inches



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JAPAN	USA	EU	CHINA
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CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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